1.5 A, 40 V Schottky Barrier Diode

These Schottky barrier diodes are optimized for low forward voltage drop and low leakage current and are offered in a Chip Scale Package (CSP) to reduce board space. The low thermal resistance enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Low Forward Voltage Drop 540 mV (Typ.) @ $I_F = 1.5 \text{ A}$
- Low Reverse Current $20 \ \mu A$ (Typ.) @ V_R = $40 \ V$
- 1.5 A of Continuous Forward Current
- ESD Rating Human Body Model: Class 3B
 - Machine Model: Class C
- High Switching Speed
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

MAXIMUM RATINGS

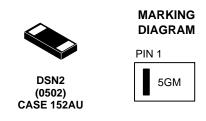
I	Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	V	
Forward Current (١ _F	1.5	А	
Forward Surge Cu	I _{FSM}	13	A	
Repetitive Peak F (Pulse Wave = 1 s	I _{FRM}	3	A	
ESD Rating:	Human Body Model Machine Model	ESD	> 8 > 400	kV V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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5G = Specific Device Code M = Date Code

PIN CONNECTIONS

1 0 2 CATHODE ANODE

ORDERING INFORMATION

Device	Package	Shipping [†]
NSR15405NXT5G	DSN2 (Pb-Free)	5000 / Tape & Reel

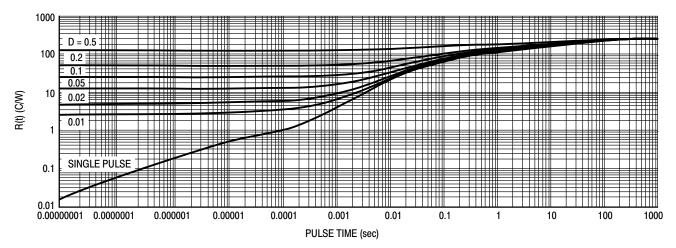
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction–to–Ambient (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$	R _{θJA} P _D			255 490	°C/W mW
Thermal Resistance Junction–to–Ambient (Note 2) Total Power Dissipation @ $T_A = 25^{\circ}C$	R _{θJA} P _D			95 1.32	°C/W W
Storage Temperature Range	T _{stg}			-40 to +125	°C
Junction Temperature	TJ			+150	°C

1. Mounted onto a 4 in square FR-4 board 50 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

2. Mounted onto a 4 in square FR-4 board 650 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.





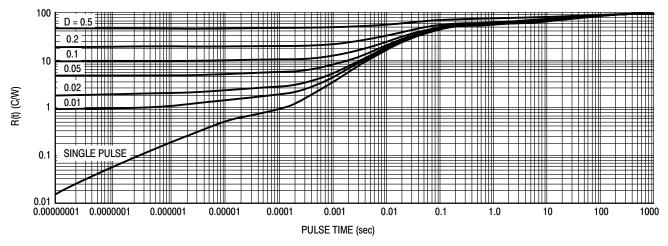
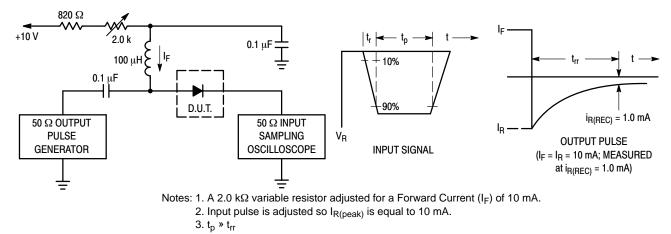


Figure 2. Thermal Response (Note 2)

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage $(V_R = 10 V)$ $(V_R = 40 V)$	I _R		2 20	10 75	μΑ
Forward Voltage $(I_F = 10 \text{ mA})$ $(I_F = 100 \text{ mA})$ $(I_F = 500 \text{ mA})$ $(I_F = 1 \text{ A})$ $(I_F = 1.5 \text{ A})$	VF	- - - - -	250 320 410 480 540	290 360 450 520 590	mV
Total Capacitance ($V_R = 2.0 \text{ V}$, f = 1.0 MHz)	CT	-	85	-	pF
Reverse Recovery Time ($I_F = I_R = 10$ mA, $I_{R(REC)} = 1.0$ mA, Figure 3)	t _{rr}	-	33	-	ns
Peak Forward Recovery Voltage ($I_F = 100 \text{ mA}, t_r = 20 \text{ ns}, \text{ Figure 4}$)	V _{FRM}	_	460	_	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





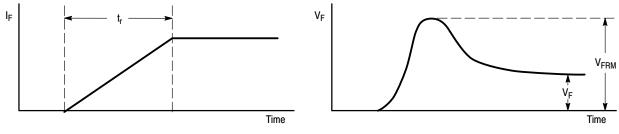
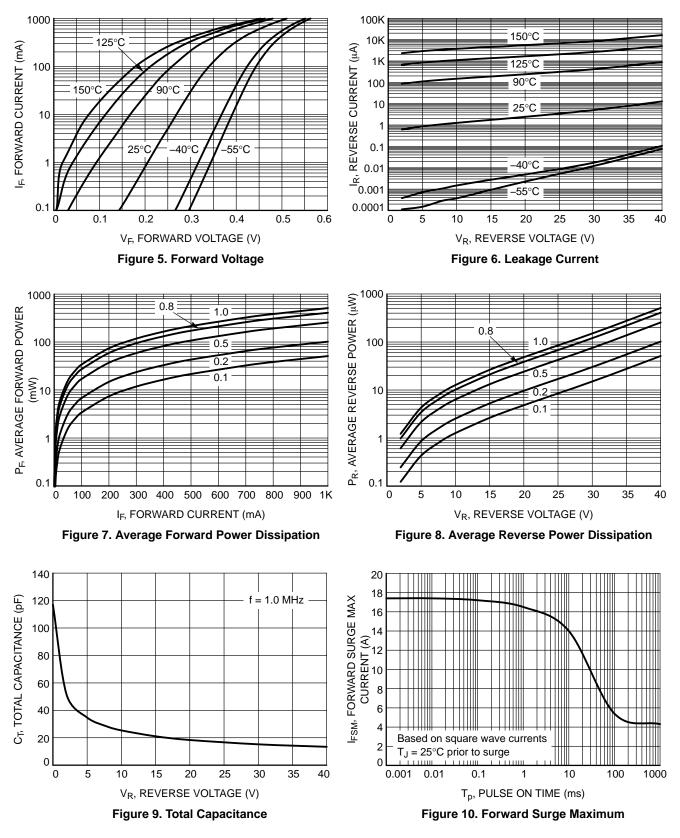
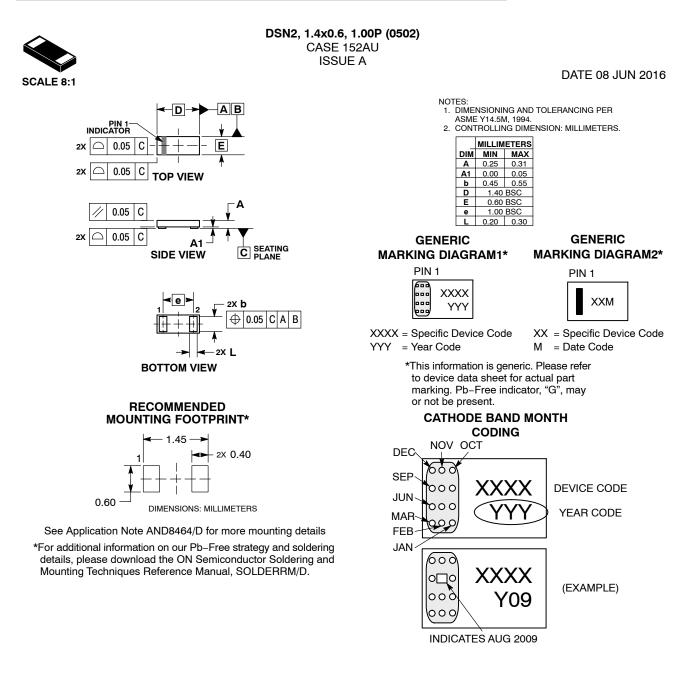


Figure 4. Peak Forward Recover Voltage Definition

TYPICAL CHARACTERISTICS







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